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APPLICATION NO.	F.	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/824,086	09/824,086 04/02/2001		Tony Albrecht	P01,0121	9330
26574	7590	03/10/2004		EXAMINER	
SCHIFF HA	•		LEUNG, QUYEN PHAN		
PATENT DI 6600 SEARS			ART UNIT	PAPER NUMBER	
CHICAGO,	IL 6060	6-6473	2828		
				DATE MAILED: 03/10/2004	4

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)					
Office Action Summary		09/824,086	ALBRECHT ET AL.					
		Examiner	Art Unit	,				
		Quyen P. Leung	2828					
Period f	The MAILING DATE of this communication a or Reply	ppears on the cover sheet wi	th the correspondence addre	ess				
A SH THE - Exte afte - If th - If No - Faili Any	HORTENED STATUTORY PERIOD FOR REF MAILING DATE OF THIS COMMUNICATION ensions of time may be available under the provisions of 37 CFR r SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a round of the provision of the pr	N. 1.136(a). In no event, however, may a reply within the statutory minimum of thirt od will apply and will expire SIX (6) MON tute, cause the application to become AB	reply be timely filed by (30) days will be considered timely. ITHS from the mailing date of this common that it is common that is used.	nunication.				
Status								
1)⊠	Responsive to communication(s) filed on 14	November 2003.						
2a)□		nis action is non-final.						
3)□	·—		ers, prosecution as to the m	erits is				
,—	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposit	tion of Claims							
4)⊠	Claim(s) 1-25 is/are pending in the application	on.						
,	4a) Of the above claim(s) is/are withdown							
5)	Claim(s) is/are allowed.							
·	Claim(s) <u>1-25</u> is/are rejected.							
-	Claim(s) is/are objected to.							
· ·	Claim(s) are subject to restriction and	l/or election requirement.						
Applicat	tion Papers							
9)	The specification is objected to by the Exami	ner.						
	The drawing(s) filed on is/are: a) a		by the Examiner.					
,	Applicant may not request that any objection to the							
	Replacement drawing sheet(s) including the corre			1.121(d).				
11)	The oath or declaration is objected to by the		• • •					
Priority	under 35 U.S.C. § 119							
<u> </u>	Acknowledgment is made of a claim for foreign	an priority under 35 U.S.C. 8	5 119(a)-(d) or (f)					
	□ All b) Some * c) None of:	gri priority dilaci do d.c.c. 5	; 110(a) (a) or (i).					
Ξ,	1. Certified copies of the priority docume	ents have been received						
	2. Certified copies of the priority docume		nnlication No					
	3. Copies of the certified copies of the pr		· ·	ane				
	application from the International Bure	•	TOOTTOO IT THO TAMONAL OR	190				
* :	See the attached detailed Office action for a li	, , , ,	received.					
		·						
Attach	**(a)							
Attachmer 1) ⊠ Noti	nt(s) ce of References Cited (PTO-892)	4) Intension S	Summary (PTO-413)					
_	ce of Draftsperson's Patent Drawing Review (PTO-948)		s)/Mail Date					
3) 🔲 Infor	mation Disclosure Statement(s) (PTO-1449 or PTO/SB/0er No(s)/Mail Date	5) Notice of Ir 6) Other:	nformal Patent Application (PTO-15 	2)				

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 11/14/2003 has been entered.

Response to Arguments

2. Applicant's arguments with respect to claims 1-25 have been considered but are most in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 112

- 3. The following is a quotation of the second paragraph of 35 U.S.C. 112:
 The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 4. Claims 1-25 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.
- 5. Claims 1-25 are rejected under 35 U.S.C. 112, second paragraph, as being incomplete for omitting essential structural cooperative relationships of elements, such omission amounting to a gap between the necessary structural connections. See MPEP § 2172.01. The omitted structural cooperative relationships are: between the external resonator and the radiation-generating quantum well structure.

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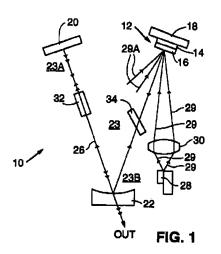
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6. Claim 3 recites the limitation "region being formed **on a basis** of a current injection path" in lines 5-6. It is unclear what is meant by it.

7. Claim 4 recites the limitation "region that is being defined **on a basis** of a current injection path" in lines 5-6. It is unclear what is meant by it.

Claim Rejections - 35 USC § 103

- 8. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 9. Claims 1-25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Caprara et al (5,991,318) in view of Kinoshita (6,535,537). Caprara et al discloses the claimed invention except for the pump radiation source (28) being on the common substrate



[57] ABSTRACT

An intracavity, frequency-doubled, external-cavity, optically-pumped semiconductor laser in accordance with the present invention includes a monolithic surface-emitting semiconductor layer structure including a Bragg mirror portion and a gain portion. An external mirror and the Bragg-mirror portion define a laser resonant-cavity including the gain-portion of the semiconductor layer structure. A birefringent filter is located in the resonant-cavity for selecting a frequency of the laser-radiation within a gain bandwidth characteristic of semiconductor structure. An optically-nonlinear crystal is located in the resonant-cavity between the birefringent filter and the external mirror and arranged to double the selected frequency of laser-radiation.

as the radiation generating quantum well structure (16). Kinoshita teaches the pump radiation source being on the common substrate as the radiation generating quantum

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well structure for the advantageous benefit of providing

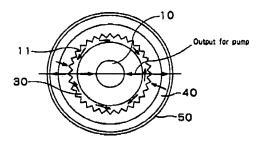


FIG. 1A

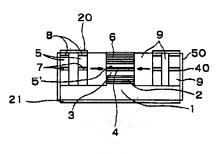


FIG. 1B

high performance, optically pumped, surface

emitting type of light emitting element that can also be manufactured extremely efficiently (see col. 2 lines 10-14).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to have the pump radiation source being on the common substrate as the radiation generating quantum well structure, since it has been held that forming in one piece an article which has formerly been formed in two pieces and put together involves only routine skill in the art. *Howard v. Detroit Stove Works*, 150 U.S. 164 (1893).

Furthermore, it would have been obvious to one of ordinary skill to modify

Caprara et al by having the pump radiation source being on the common substrate as

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the radiation generating quantum well structure, as taught by Kinoshita, for the advantageous benefit of providing high performance, optically pumped, surface emitting type of light emitting element that can also be manufactured extremely efficiently.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Quyen P. Leung whose telephone number is (571)272-1943. The examiner can normally be reached on 9-5:30, M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Paul Ip can be reached on (571)272-1941. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

> Primary Examiner Art Unit 2828

QPL